1. General description

Planar Maximum Efficiency General Application (MEGA) Schottky barrier rectifier with an integrated guard ring for stress protection, encapsulated in a SOD123W small and flat lead Surface-Mounted Device (SMD) plastic package.

2. Features and benefits

- Extremely low leakage current I_R = 235 nA
- Average forward current: I_{F(AV)} ≤ 2 A
- Reverse voltage: V_R ≤ 60 V
- Low forward voltage V_F = 600 mV
- High power capability due to clip-bonding technology
- High temperature T_i ≤ 175 °C
- Small and flat lead SMD plastic package
- AEC-Q101 qualified

3. Applications

- Low voltage rectification
- High efficiency DC-to-DC conversion
- Switch mode power supply
- Reverse polarity protection
- Low power consumption applications

4. Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
I _{F(AV)}	average forward current	δ = 0.5; f = 20 kHz; $T_{sp} \le$ 165 °C; square wave	-	-	2	Α
V_R	reverse voltage	T _j = 25 °C	-	-	60	V
V _F	forward voltage	I_F = 2 A; t_p ≤ 300 μs; δ ≤ 0.02; T_j = 25 °C	-	600	670	mV
I _R	reverse current	$V_R = 60 \text{ V}; t_p \le 300 \mu\text{s}; \delta \le 0.02;$ $T_j = 25 ^{\circ}\text{C}$	-	235	700	nA





5. Pinning information

Table 2. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	K	cathode[1]	1 2	1 -2
2	А	anode	SOD123W	sym001

^[1] The marking bar indicates the cathode.

6. Ordering information

Table 3. Ordering information

Type number	Package					
	Name	Description	Version			
PMEG6020AELR	SOD123W	plastic surface mounted package; 2 leads	SOD123W			

7. Marking

Table 4. Marking codes

Type number	Marking code
PMEG6020AELR	KE

8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Max	Unit
V_R	reverse voltage	T _j = 25 °C		-	60	V
I _F	forward current	T _{sp} = 160 °C; δ = 1		-	2.83	Α
I _{F(AV)}	average forward current	δ = 0.5; f = 20 kHz; $T_{amb} \le 95$ °C; square wave	[1]	-	2	A
		δ = 0.5; f = 20 kHz; T _{sp} \leq 165 °C; square wave		-	2	A
I _{FSM}	non-repetitive peak forward current	t_p = 8 ms; $T_{j(init)}$ = 25 °C; square wave		-	50	A
P _{tot}	total power dissipation	T _{amb} ≤ 25 °C	[2]	-	680	mW
			[3]	-	1150	mW
			[1]	-	2140	mW
T _j	junction temperature			-	175	°C
T _{amb}	ambient temperature			-55	175	°C
T _{stg}	storage temperature			-65	175	°C

- [1] Device mounted on a ceramic Printed-Circuit Board (PCB), Al₂O₃, standard footprint.
- [2] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.
- Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for cathode 1 cm².

9. Thermal characteristics

Table 6. Thermal characteristics

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
from	thermal resistance		[1][2]	-	-	220	K/W
	from junction to		[1][3]	-	-	130	K/W
	ambient		[1][4]	-	-	70	K/W
R _{th(j-sp)}	thermal resistance from junction to solder point		[5]	-	-	18	K/W

- [1] For Schottky barrier diodes thermal runaway has to be considered, as in some applications the reverse power losses P_R are a significant part of the total power losses.
- [2] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.
- Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for cathode 1 cm².
- [4] Device mounted on a ceramic PCB, Al₂O₃, standard footprint.
- [5] Soldering point of cathode tab.

PMEG6020AELR

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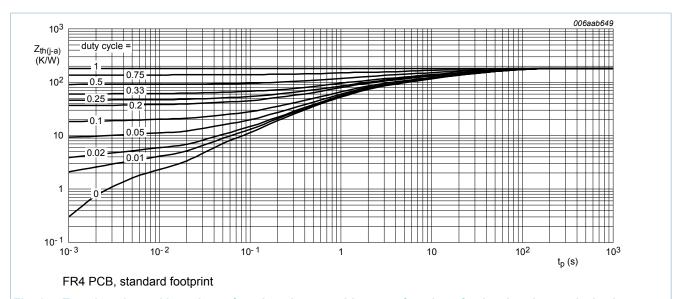


Fig. 1. Transient thermal impedance from junction to ambient as a function of pulse duration; typical values

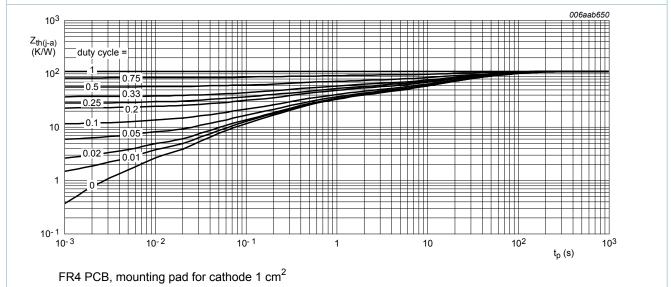
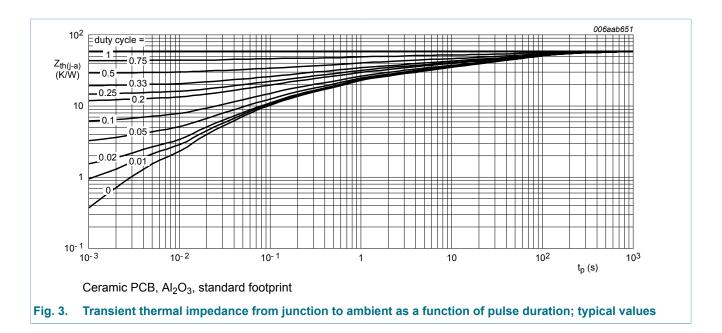


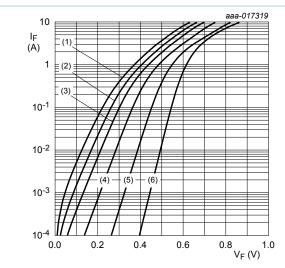
Fig. 2. Transient thermal impedance from junction to ambient as a function of pulse duration; typical values



10. Characteristics

Table 7. Characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V _{(BR)R}	reverse breakdown voltage	I_R = 1 mA; T_j = 25 °C; t_p = 300 μs; $δ$ = 0.02	60	-	-	V
V _F	forward voltage	I_F = 0.1 A; t_p ≤ 300 μs; δ ≤ 0.02; T_j = 25 °C	-	450	510	mV
		I_F = 0.5 A; t_p ≤ 300 μs; δ ≤ 0.02; T_j = 25 °C	-	510	570	mV
		I_F = 0.7 A; t_p ≤ 300 μs; δ ≤ 0.02; T_j = 25 °C	-	525	590	mV
		I_F = 1 A; t_p ≤ 300 μs; δ ≤ 0.02; T_j = 25 °C	-	545	610	mV
		I_F = 1.6 A; t_p ≤ 300 μs; δ ≤ 0.02; T_j = 25 °C	-	580	650	mV
		I_F = 2 A; t_p ≤ 300 μs; δ ≤ 0.02; T_j = 25 °C	-	600	670	mV
		I_F = 2 A; t_p ≤ 300 μs; δ ≤ 0.02; T_j = 125 °C	-	510	630	mV
I _R	reverse current	$V_R = 10 \text{ V}; t_p \le 300 \mu\text{s}; \delta \le 0.02;$ $T_j = 25 ^{\circ}\text{C}$	-	15	-	nA
		$V_R = 40 \text{ V}; t_p \le 300 \mu\text{s}; \delta \le 0.02;$ $T_j = 25 ^{\circ}\text{C}$	-	50	-	nA
		V_R = 60 V; t_p ≤ 300 μs; δ ≤ 0.02; T_j = 25 °C	-	235	700	nA
		V_R = 60 V; t_p ≤ 300 μs; δ ≤ 0.02; T_j = 125 °C	-	285	1400	μA
C_d	diode capacitance	V _R = 1 V; f = 1 MHz; T _j = 25 °C	-	220	-	pF
		V _R = 4 V; f = 1 MHz; T _j = 25 °C	-	135	-	pF
		V _R = 10 V; f = 1 MHz; T _j = 25 °C	-	88	-	pF
rr	reverse recovery time	$I_F = 0.5 \text{ A}; I_R = 0.5 \text{ A}; I_{R(meas)} = 0.1 \text{ A};$ $T_j = 25 \text{ °C}$	-	9	-	ns
V_{FRM}	peak forward recovery voltage	$I_F = 0.5 \text{ A}; T_j = 25 \text{ °C}; dI_F/dt = 20 \text{ A/}\mu\text{s}$	-	580	-	mV



- (1) $T_i = 175 \,^{\circ}C$
- (2) $T_i = 150 \, ^{\circ}C$
- (3) $T_i = 125 \,^{\circ}C$
- (4) $T_i = 85 \,^{\circ}C$
- (5) $T_i = 25 \, ^{\circ}C$
- (6) $T_i = -40 \, ^{\circ}C$

Fig. 4. Forward current as a function of forward voltage; typical values

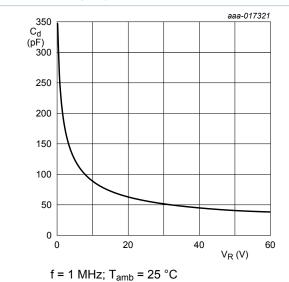
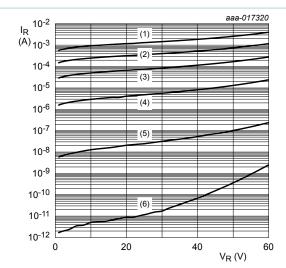
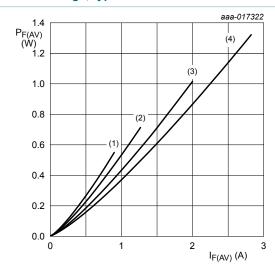


Fig. 6. Diode capacitance as a function of reverse voltage; typical values



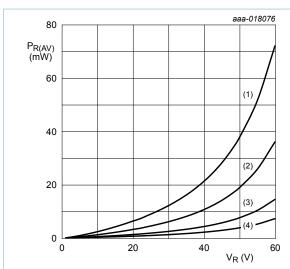
- (1) $T_i = 175 \, ^{\circ}C$
- (2) $T_j = 150 \, ^{\circ}\text{C}$
- (3) $T_i = 125 \,^{\circ}C$
- (4) $T_i = 85 \, ^{\circ}C$
- (5) $T_i = 25 \,^{\circ}C$
- (6) $T_i = -40 \,^{\circ}\text{C}$

Fig. 5. Reverse current as a function of reverse voltage; typical values



- T_i = 175 °C
- $(1) \delta = 0.1$
- (2) $\delta = 0.2$
- $(3) \delta = 0.5$
- $(4) \delta = 1$

Fig. 7. Average forward power dissipation as a function of average forward current; typical values



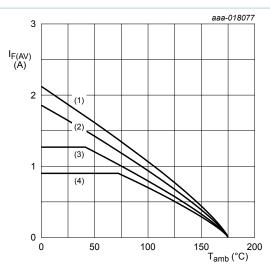
(1)
$$\delta = 1$$
 (DC)

(2)
$$\delta = 0.5$$
; $f = 20 \text{ kHz}$

(3)
$$\delta$$
 = 0.2; f = 20 kHz

(4)
$$\delta$$
 = 0.1; f = 20 kHz

Fig. 8. Average reverse power dissipation as a function of reverse voltage; typical values



FR4 PCB, standard footprint

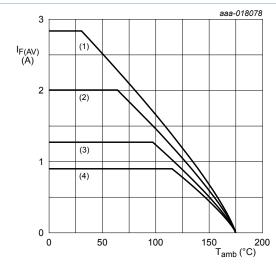
(1)
$$\delta$$
 = 1; DC

(2)
$$\delta$$
 = 0.5; f = 20 kHz

(3)
$$\delta$$
 = 0.2; f = 20 kHz

(4)
$$\delta = 0.1$$
; $f = 20 \text{ kHz}$

Fig. 9. Average forward current as a function of ambient temperature; typical values



FR4 PCB, mounting pad for cathode 1 cm²

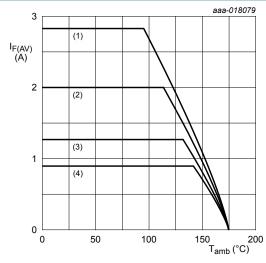
(1)
$$\delta$$
 = 1; DC

(2)
$$\delta = 0.5$$
; $f = 20 \text{ kHz}$

(3)
$$\delta = 0.2$$
; $f = 20 \text{ kHz}$

(4)
$$\delta = 0.1$$
; $f = 20 \text{ kHz}$

Fig. 10. Average forward current as a function of ambient temperature; typical values



Ceramic PCB, Al₂O₃, standard footprint

$$T_i = 175 \,{}^{\circ}\text{C}$$

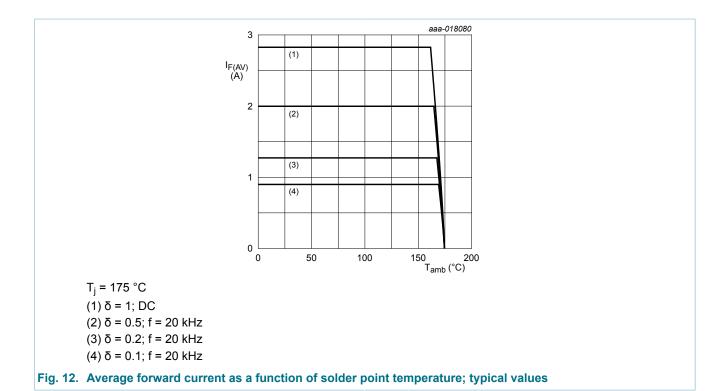
(1)
$$\delta$$
 = 1; DC

(2)
$$\delta$$
 = 0.5; f = 20 kHz

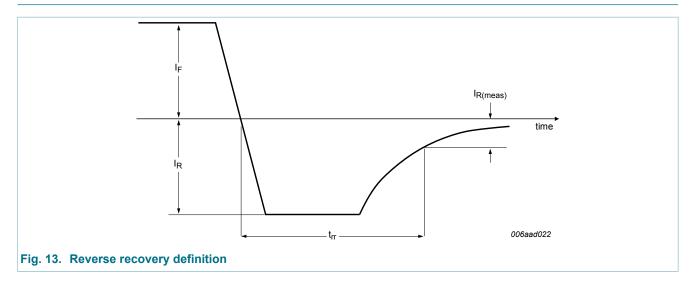
(3)
$$\delta$$
 = 0.2; f = 20 kHz

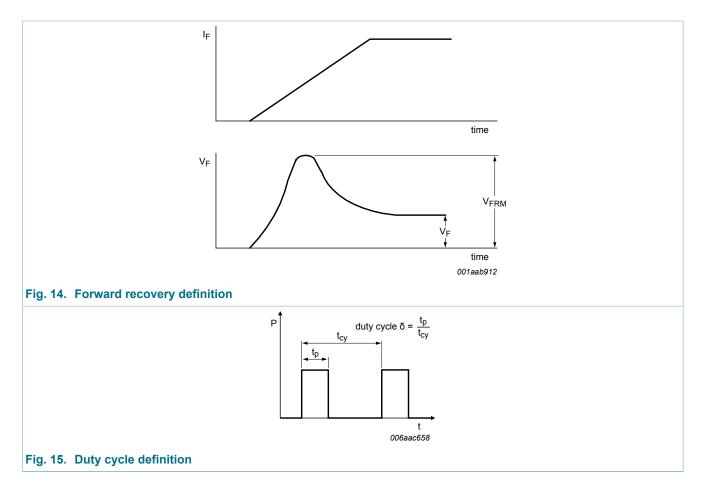
(4)
$$\delta$$
 = 0.1; f = 20 kHz

Fig. 11. Average forward current as a function of ambient temperature; typical values



11. Test information



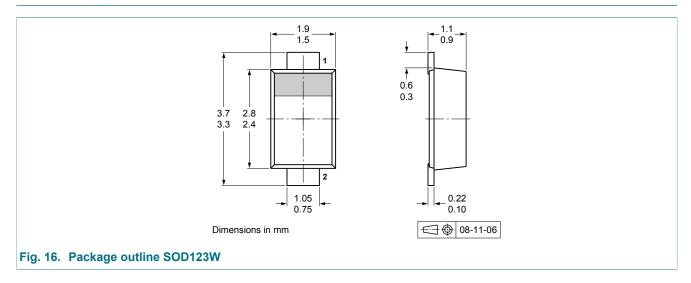


The current ratings for the typical waveforms are calculated according to the equations: $I_{F(AV)} = I_M \times \delta$ with I_M defined as peak current, $I_{RMS} = I_{F(AV)}$ at DC, and $I_{RMS} = I_M \times \sqrt{\delta}$ with I_{RMS} defined as RMS current.

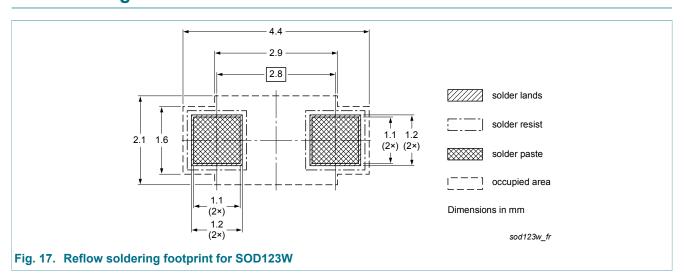
11.1 Quality information

This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard Q101 - Stress test qualification for discrete semiconductors, and is suitable for use in automotive applications.

12. Package outline



13. Soldering



14. Revision history

Table 8. Revision history

Data sheet ID	Release date	Data sheet status	Change notice	Supersedes		
PMEG6020AELR v.2	20150619	Product data sheet	-	PMEG6020AELR v.1		
Modification:	editorial correction of package name in section 1					
PMEG6020AELR v.1	20150507	Product data sheet	-	-		

15. Legal information

15.1 Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
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